



2SA1706/2SC4486

High-Current Switching Applications

Applications

- Voltage regulators, relay drivers, lamp drivers.

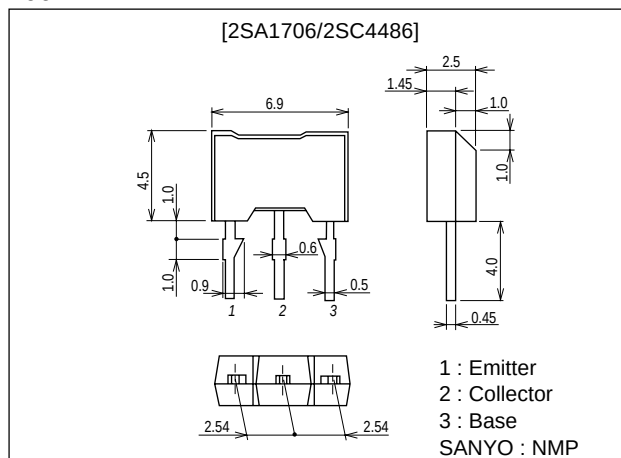
Features

- Adoption of FBET, MBIT processes.
- Large current capacity and wide ASO.
- Fast switching speed.

Package Dimensions

unit:mm

2064A



() : 2SA1706

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)60	V
Collector-to-Emitter Voltage	V_{CEO}		(-)50	V
Emitter-to-Base Voltage	V_{EBO}		(-)6	V
Collector Current	I_C		(-)2	A
Collector Current (Pulse)	I_{CP}		(-)4	A
Collector Dissipation	P_C		1	W
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)50\text{V}, I_E=0$			(-)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4\text{V}, I_C=0$			(-)100	nA
DC Current Gain	h_{FE1}	$V_{CE}=(-)2\text{V}, I_C=(-)100\text{mA}$	100*		400*	
	h_{FE2}	$V_{CE}=(-)2\text{V}, I_C=(-)1.5\text{A}$	40			
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10\text{V}, I_C=(-)50\text{mA}$		150		MHz

* : The 2SA1706/2SC4486 are classified by 100mA h_{FE} as follows :

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Rank	R	S	T
h_{FE}	100 to 200	140 to 280	200 to 400

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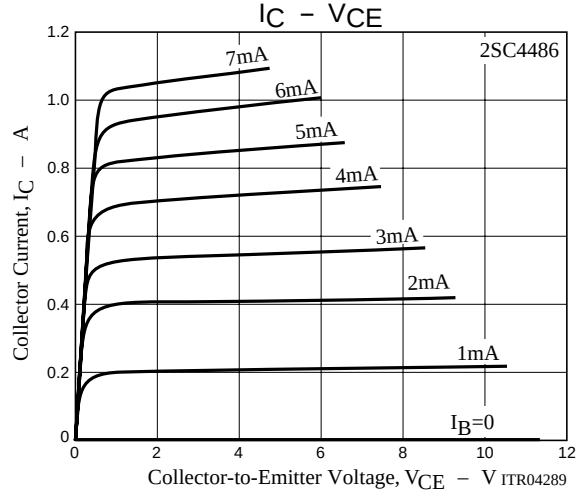
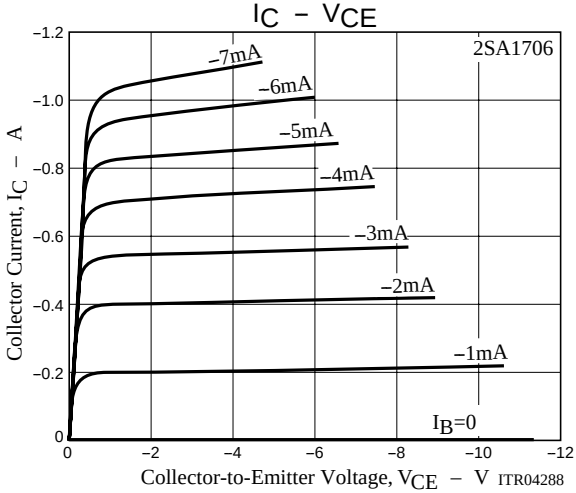
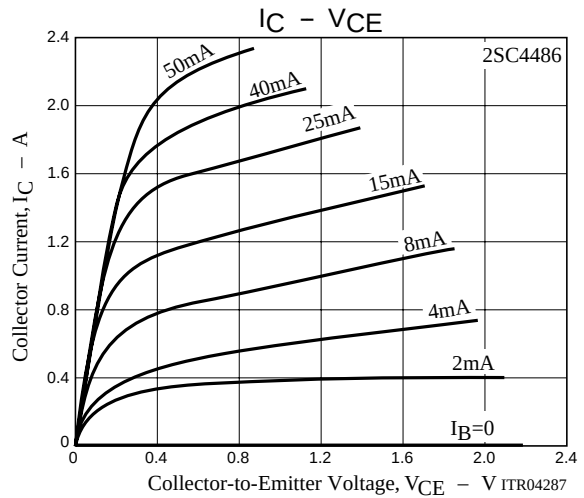
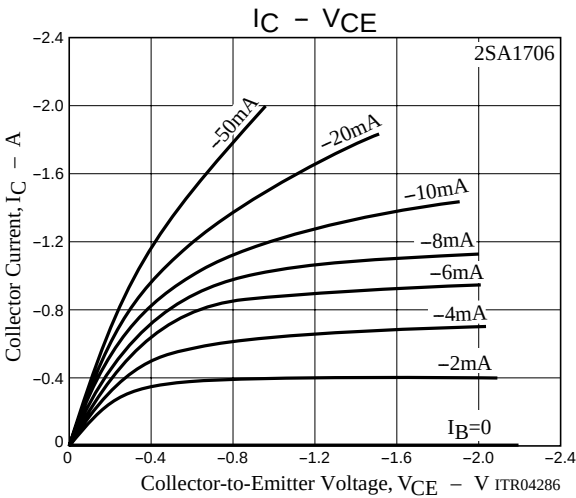
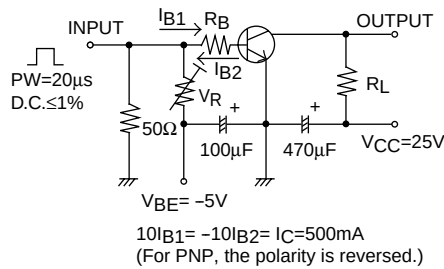
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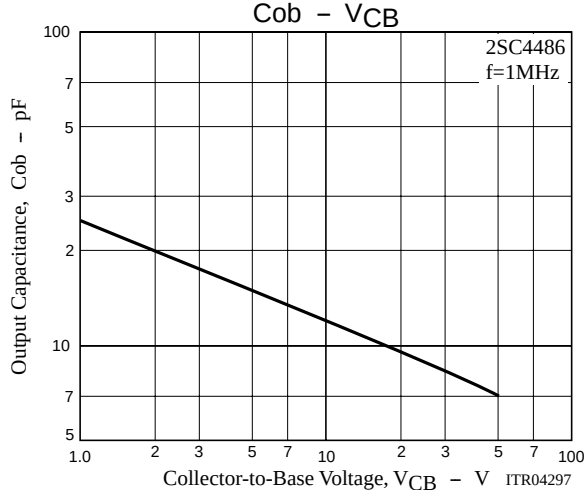
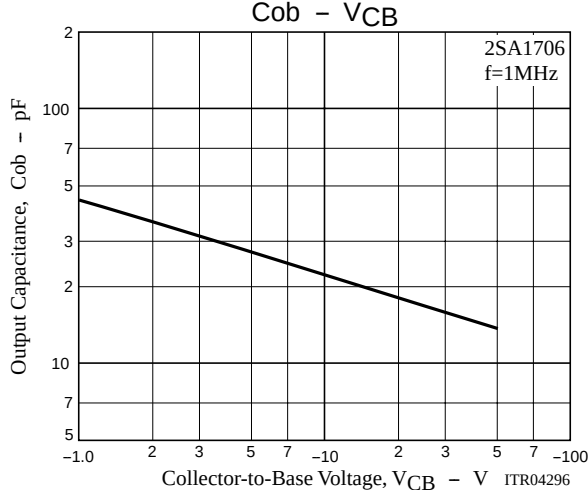
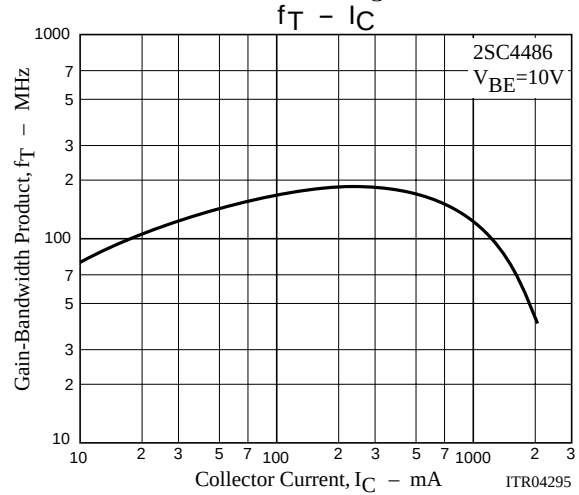
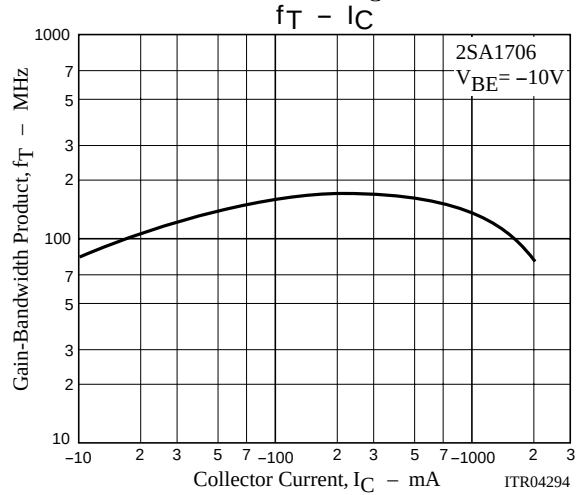
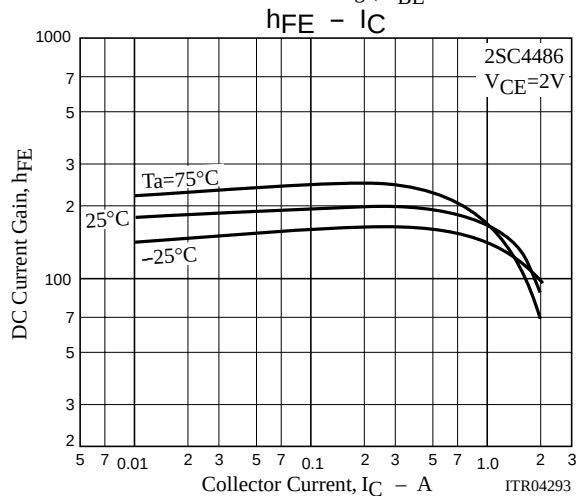
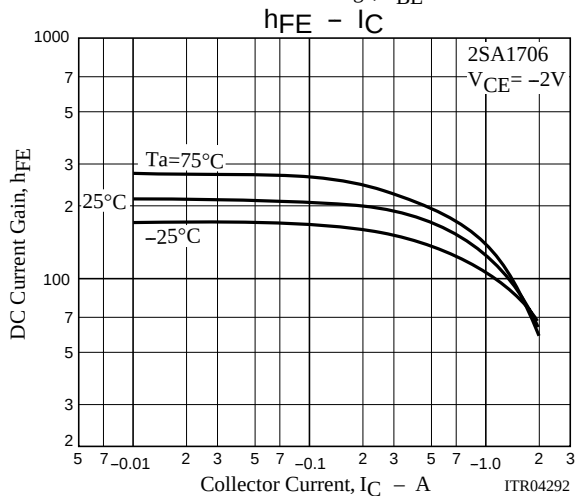
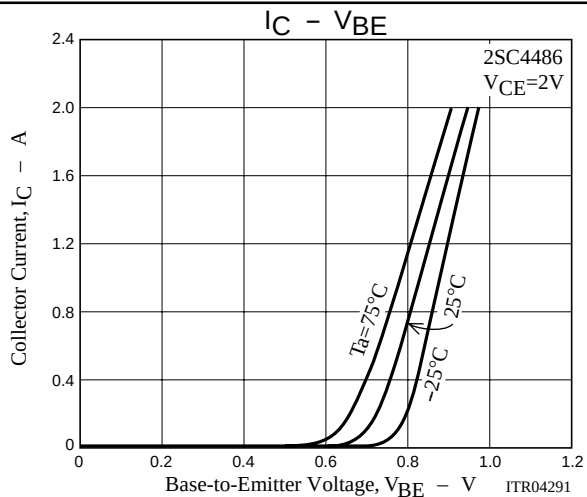
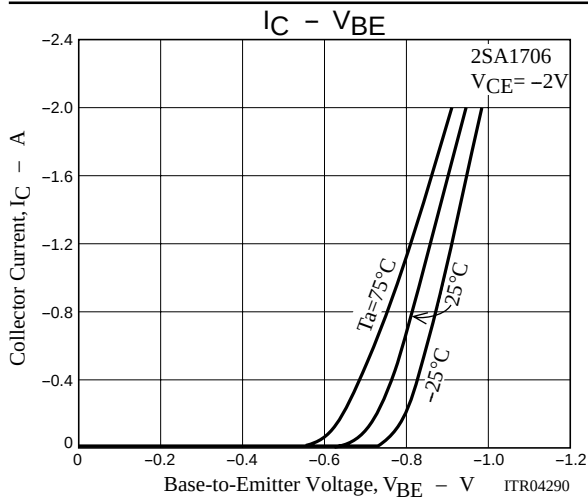
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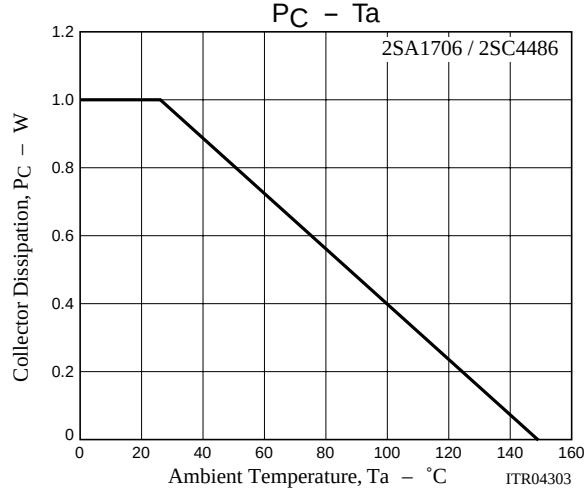
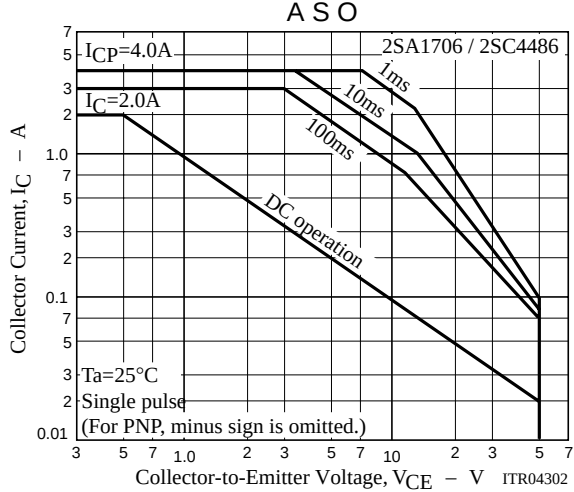
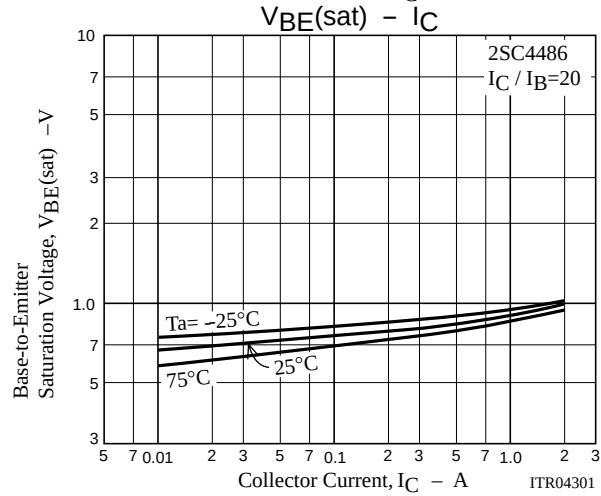
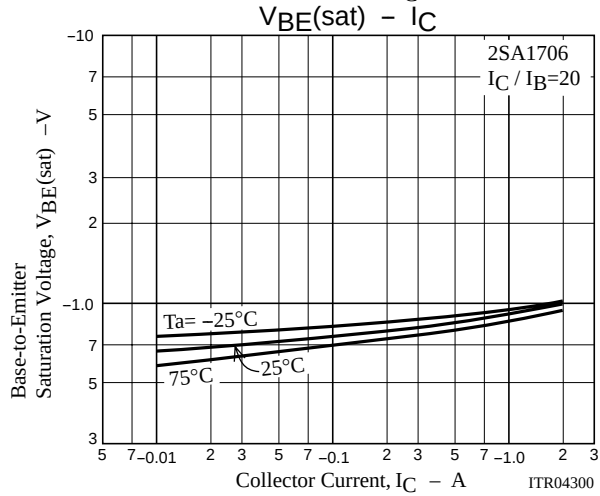
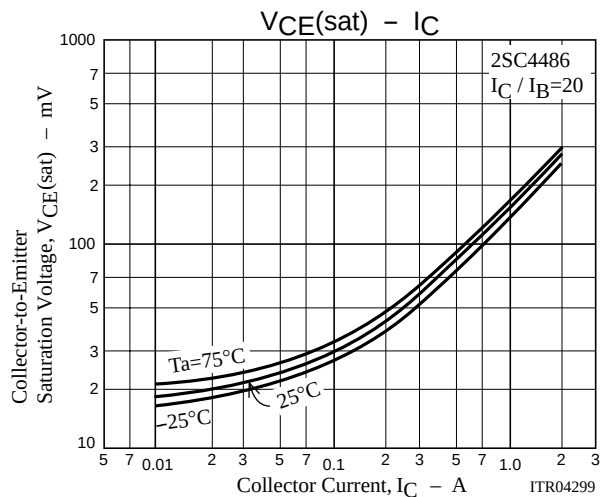
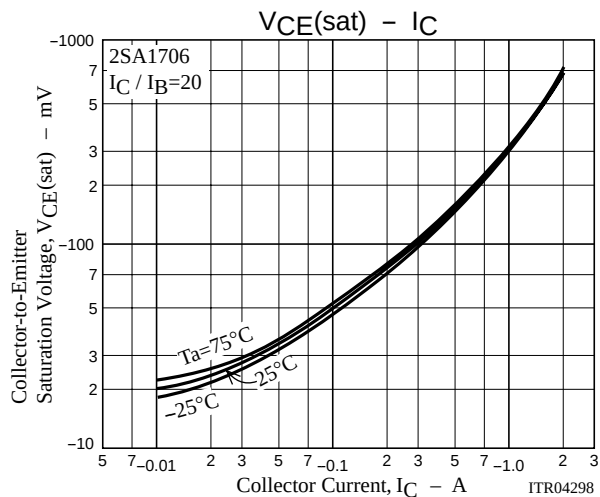
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)1A, I_B=(-)50mA$		(-0.3)	(-0.7)	V
				0.15	0.4	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)1A, I_B=(-)50mA$		(-)0.9	(-)1.2	V
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		(22)12		pF
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-)60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-)50			V
Emitter-to-Base Breakdown Votage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-)6			V
Turn-ON Time	t_{on}	See specified Test Circuit		60		ns
Storage Time	t_{stg}	See specified Test Circuit		(450)		ns
				550		ns
Fall Time	t_f	See specified Test Circuit		30		ns

Switching Time Test Circuit



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